NSN 5961-01-039-0333

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-039-0333 **Inclosure Material:** Plastic **Overall Length:** Between 0.500 inches and 0.540 inches **Overall Height:** Between 0.165 inches and 0.190 inches **Overall Width:** Between 0.380 inches and 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 12.00 amperes forward current, total rms nanoamperes **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius case **Special Features:** Mtg tab included; junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0